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# Solitons in dispersion-inverted *AlGaAs* nanowires

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**Abstract:** We demonstrate that optical solitons can exist in dispersion-inverted highly-nonlinear *AlGaAs* nanowires. This is accomplished by strongly reversing the dispersion of these nano-structures to anomalous over a broad frequency range. These self-localized waves are possible at very low power levels and can form in millimeter long nanowire structures. The intensity and spectral evolution of solitons propagating in such *AlGaAs* nanowaveguides is investigated in the presence of loss, multiphoton absorption and higher-order dispersion.

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**OCIS codes:** (190.5530) pulse propagation and solitons, (190.4370) Nonlinear optics, fibers, (260.2030) Dispersion.

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## 1. Introduction

The interaction of light with matter on a nanometer scale opens up new opportunities which may have far reaching implications in telecommunications, computation, biophotonics, and sensing technologies [1]. Lately, single-mode sub-wavelength waveguides or nanowires have been realized in several material systems [2-11]. Such optical nanowire structures are capable of providing superior light confinement and are thus ideal for nonlinear optics applications [12]. Clearly, of interest will be to fabricate such nanowires using high contrast, highly nonlinear materials, such as *AlGaAs*-known to exhibit a nonlinearity that is three orders of magnitude higher than that of silica glass [13,14]. Apart from being highly nonlinear, *AlGaAs* nanowires are also highly promising in terms of applications since they can be integrated with other optoelectronic components on the same wafer and thus can serve as information conduits among miniaturized devices. Quite recently, enhanced spectral broadening or SPM has been observed for the first time in  $700\mu m$  long *AlGaAs* nanowires [15]. An important question associated with this particular system is whether optical solitons are possible in *AlGaAs* nanowaveguides. This is of relevance since solitons can be used to either overcome dispersion effects or to achieve pulse compression in such nanostructures. We note that so far, optical solitons have only been observed in multi-layer *AlGaAs* structures in which the dispersion can be engineered [16,17]. Yet, in primitive weakly guiding *AlGaAs* waveguides such solutions are not possible since this material system exhibits appreciable normal dispersion in the spectral region of interest [18], i.e. for  $1.1\mu m < \lambda < 1.7\mu m$ . Here we theoretically demonstrate, that, because of high contrast, the dispersion of an air-clad *AlGaAs* nanowire can become strongly anomalous (becomes inverted), thus overcoming material dispersion limitations. This in turn may allow optical soliton formation in millimeter long structures. These solitons are possible at very low power levels (at  $\sim 5$  W) in spite of the fact that the *AlGaAs* nanowires can exhibit anomalous dispersion that is a thousand times higher than that of silica glass. The intensity and spectral evolution of these solitons is investigated in *AlGaAs* nanowaveguides in the presence of loss, multi-photon absorption, and higher-order dispersive and nonlinear effects.

## 2. *AlGaAs* Nanowire dispersion properties

To analyze the dispersion properties of *AlGaAs* nanowires, let us consider for example an  $Al_{0.2}Ga_{0.8}As$  nanorod of core radius  $a$  as shown in Fig.1(a). This particular composition ( $Al_{0.2}Ga_{0.8}As$ ) is deliberately chosen since in the neighborhood of  $\lambda = 1.55\mu m$  it is known to exhibit relatively low two-photon absorption [19]. In addition, we assume that the nanowire is air-cladded. We note that even though completely air-clad structures are rather difficult to develop these days, it is yet possible to fabricate waveguides that are mostly surrounded by air, with characteristics very similar to the one analyzed here. At this wavelength the

refractive index of  $Al_{0.2}Ga_{0.8}As$  is approximately 3.27, and the nanorod is operated at or close to the single-mode regime. In general, the nanowire dispersion relation is given by [20]:

$$\left[ \frac{J'_m(u)}{uJ_m(u)} + \frac{K'_m(w)}{wK_m(w)} \right] \left[ \frac{J'_m(u)}{uJ_m(u)} + \left( \frac{n_{clad}}{n_{core}} \right)^2 \frac{K'_m(w)}{wK_m(w)} \right] = m^2 \left( \frac{1}{u^2} + \frac{1}{w^2} \right) \left( \frac{1}{u^2} + \left( \frac{n_{clad}}{n_{core}} \right)^2 \frac{1}{w^2} \right) \quad (1)$$

In Eq.(1)  $J_m(u)$  is a Bessel function of the first kind and of order  $m$  and similarly  $K_m(w)$  is a modified Bessel function, and primes represent derivatives with respect to the argument.  $u = ak_o \sqrt{n_{core}^2 - n_{eff}^2}$ ,  $w = ak_o \sqrt{n_{eff}^2 - n_{clad}^2}$  where  $k_o = 2\pi/\lambda$  is the free space wavevector and  $n_{eff}$  is the effective refractive index of the mode [20].  $n_{core}$  is the core index and  $n_{clad} = 1$  since the exterior medium is air. The wavelength dependence of the refractive index is accounted by using the Sellmeier expansion of  $Al_xGa_{1-x}As$ , i.e [18]:

$$n_{core}^2(x, T, \lambda) = A(x, T) + \frac{C_0(x)}{E_0^2(x, T) - 1/\lambda^2} + \frac{C_1(x)}{E_1^2(x, T) - 1/\lambda^2} \quad (2)$$

In general, the constants  $A$ ,  $C_0$ ,  $C_1$ ,  $E_0$  and  $E_1$  depend on the  $Al$  composition ( $x$ ), the temperature  $T$ , and the free space wavelength  $\lambda$ . Here all calculations were carried out at room temperature.

The dispersion properties of the fundamental mode  $HE_{11}$  of such a nano-structure are obtained by numerically solving Eq. (1) for  $m = 1$ , with the core index evaluated at each frequency step from Eq. (2). The dispersion coefficient  $\beta'' = d^2\beta/d\omega^2$  of an  $Al_{0.2}Ga_{0.8}As$  nanowire is shown in Fig.1(b) in units of  $ps^2/m$  for different core radii. In this same figure, the bulk  $Al_{0.2}Ga_{0.8}As$  dispersion is also included for comparison.

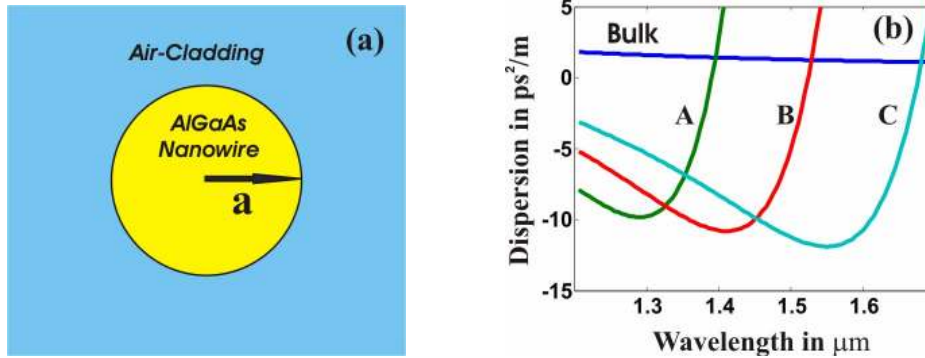


Fig. 1. (a) a nanowire structure; (b) group velocity dispersion  $\beta''$  of an  $Al_{0.2}Ga_{0.8}As$  nanowire when its radius is (A) 160, (B) 175 and (C) 193 nm. Bulk dispersion of  $Al_{0.2}Ga_{0.8}As$  is also shown.

It is important to note that because of the strong index contrast of the  $AlGaAs$  nanowaveguide and the resulting field confinement, the waveguide dispersion dominates and as a result the dispersion can become inverted and strongly anomalous [4,21]. In fact for  $a = 193nm$ , the dispersion of such a nanorod can reach very high values, as high as  $-12ps^2/m$ , which is  $10^3$  times higher than that of a standard silica fiber at  $1.55\mu m$ .

Parenthetically, we would like to point out that these same structures can also lead to very high normal dispersion. Figure 2(a) depicts the total dispersion of an  $Al_{0.2}Ga_{0.8}As$  nanorod when its radius is  $a = 160nm$ . As one can see, the anomalous dispersion of this structure (also shown in Fig. 1(b) for  $\lambda \leq 1.4\mu m$ ) is followed by a region of strong normal dispersion especially at  $1.55\mu m$ . In fact around  $1.55\mu m$  the dispersion is approximately  $\beta'' = 80ps^2/m$ . Thus the dispersion of a  $2cm$  long  $AlGaAs$  nanorod will be sufficient to cancel that arising from a  $1.25km$  long anomalously dispersive fiber with group velocity dispersion  $D = 1ps/km.nm$ . In addition Fig. 2(b) shows the group index  $n_g = c/v_g$  and the effective index  $n_{eff}$  of an  $Al_{0.2}Ga_{0.8}As$  nanowire of radius  $a = 175nm$  as a function of wavelength. Note that the group index in this case can be as high as  $n_g \approx 5.52$  around  $1.55\mu m$ , which indicates “slow” light transport (because of waveguide dispersion) in spite of the fact that bulk index is 3.27 and  $n_{eff} = 1.56$ .

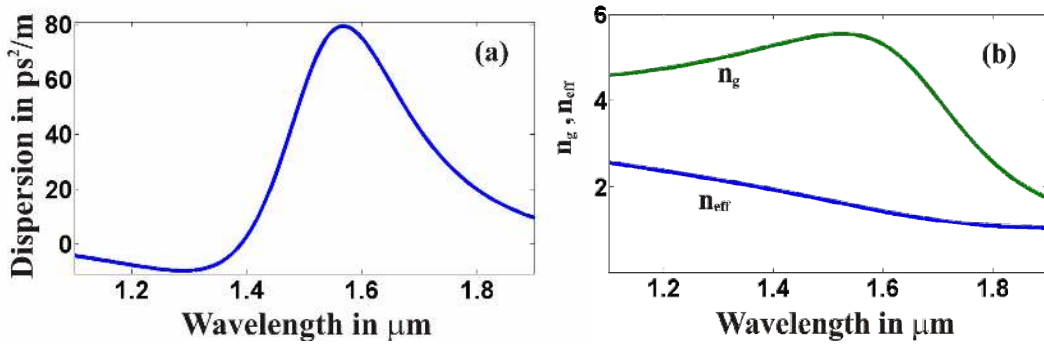


Fig. 2. (a) group velocity dispersion  $\beta''$  when  $a = 160nm$ , (b) group and effective refractive indices of an  $Al_{0.2}Ga_{0.8}As$  nanowire when  $a = 175nm$ .

For the subsequent discussion, we chose two operating points based on the designs (C) and (B) shown in Fig. 1(b). In particular the design (C) is used at  $1.55\mu m$  where the third-order dispersion is very small whereas design (B) is used at  $1.5\mu m$  where cubic dispersive effects become appreciable. The nanowire of case (C) is single-moded for  $\lambda \geq 1.57\mu m$  whereas that of (B) is monomode for  $\lambda \geq 1.42\mu m$ .

### 3. Soliton effects in AlGaAs nanowires

Nonlinear pulse propagation in such nanowire structures is modeled using the evolution equation [22]:

$$i \frac{\partial \varphi}{\partial z} + i\alpha\varphi + \sum_{m=2}^{\infty} \frac{i^m \beta^{(m)}}{m!} \frac{\partial^m \varphi}{\partial T^m} + \frac{\omega_0 n_2}{2c} \left[ |\varphi|^2 \varphi + \frac{i}{\omega_0} \frac{\partial (|\varphi|^2 \varphi)}{\partial T} \right] + i\alpha_2 |\varphi|^2 \varphi + i\alpha_3 |\varphi|^4 \varphi = 0 \quad (3)$$

In Eq.(3),  $\varphi$  represents the pulse envelope,  $T = t - z/v_g$ ,  $\alpha$  is the linear loss coefficient,  $\beta^{(m)} = \partial^m \beta / \partial \omega^m$  is the  $m^{th}$  order dispersion coefficient evaluated at the carrier angular frequency  $\omega_0 = 2\pi c / \lambda$ ,  $n_2 = (\hat{n}_2 n) / (2\eta_0)$  where  $\hat{n}_2 = 1.3 \times 10^{-13} cm^2/W$  is the

nonlinear Kerr coefficient and  $n$  is the linear refractive index of  $AlGaAs$  ( $\eta_o$  is the free space wave impedance).  $\alpha_2 = 6.5 \times 10^{-15} m/V^2$  and  $\alpha_3 = 5.63 \times 10^{-31} m^3/V^4$  are the two-photon and three-photon absorption coefficients respectively at  $\lambda \approx 1.55 \mu m$  [19]. In all cases, the dispersion curve is incorporated in Eq.(3) using a dispersion Taylor series over a broad spectral range (greatly exceeding the pulse spectrum). Here the linear loss for the field is taken to be  $\alpha = .25 cm^{-1}$ .

Figure 3(a) shows the intensity evolution of a 200 fs (FWHM) hyperbolic secant optical pulse when is launched into a 5 mm long  $Al_{0.2}Ga_{0.8}As$  nanowire of core radius  $a = 193 nm$  (corresponding to curve (C) of Fig.1(b)) at 1.55  $\mu m$ . For this design, the quadratic dispersion ( $\beta'' = -12 ps^2/m$ ) dominates the propagation process (the higher-order dispersion terms are negligible) and the dispersion length is  $\approx 1.5 mm$ , i.e., is very small. The pulse peak power in this case is approximately 5.5 W (with a 75% confinement factor), corresponding to the fundamental soliton in this nanowire structure. As Fig. 3(a) clearly indicates, this soliton can be sustained over approximately 3-4 dispersion lengths, i.e. up to a distance that is ultimately determined by the linear loss of the system. Fig. 3(b) on the other hand depicts soliton compression under similar conditions when the input power of the pulse is 8 W. For this power level, at 2 dispersion lengths, the FWHM pulsewidth becomes 175 fs. Figure 3(c) and (d) demonstrate similar results when an  $AlGaAs$  nanowire corresponding to curve (B) of Fig.1(b), is used at 1.5  $\mu m$ . Even in this case, in spite of appreciable third-order dispersion effects and multi-photon absorption, a 200 fs soliton forms at 2 W, as shown in Fig. 3(c). Soliton compression is also shown for this case in Fig. 3(d) when the input power is 2.8 W. It is important to note that in all cases ultrashort solitons in these nanowires can form within millimeters and at very low power levels.

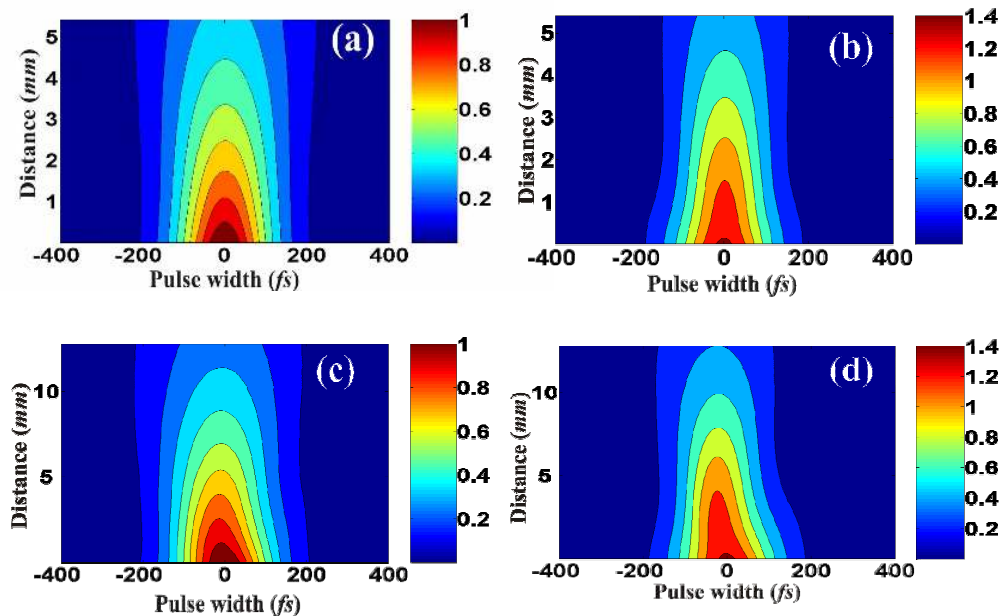


Fig. 3 Intensity evolution of a 200 fs soliton propagating in a 193 nm (radius)  $AlGaAs$  nanowire when the peak power is (a) 5.5 and (b) 8 W. Similarly, (c) and (d) depict soliton propagation and compression in a nanowire of radius 175 nm when the peak power is 2 and 2.8 W respectively.

Figure 4 depicts the power spectra that may result in an  $Al_{0.2}Ga_{0.8}As$  nanowaveguide of radius  $a = 193\text{ nm}$  when is excited at  $1.55\mu\text{m}$  with a  $200\text{ fs}$  FWHM optical pulse. When the input peak power is enough to establish an optical soliton ( $5.5\text{ W}$ ) the power spectrum remains essentially invariant during propagation as shown in Fig. 4(a). At a higher power ( $8\text{ W}$ ) the pulse undergoes compressions and thus its spectrum broadens (Fig. 4(b)). Figures 4(c) and (d) on the other hand depict the expected spectra and intensity profile of a higher order soliton at  $L \approx 5\text{ mm}$ . In this latter case, the peak power is  $50\text{ W}$  and thus corresponds to an  $N = 3$  higher order soliton solution. The splitting behavior observed in Fig. 4(d) is attributed to multi-photon absorption.

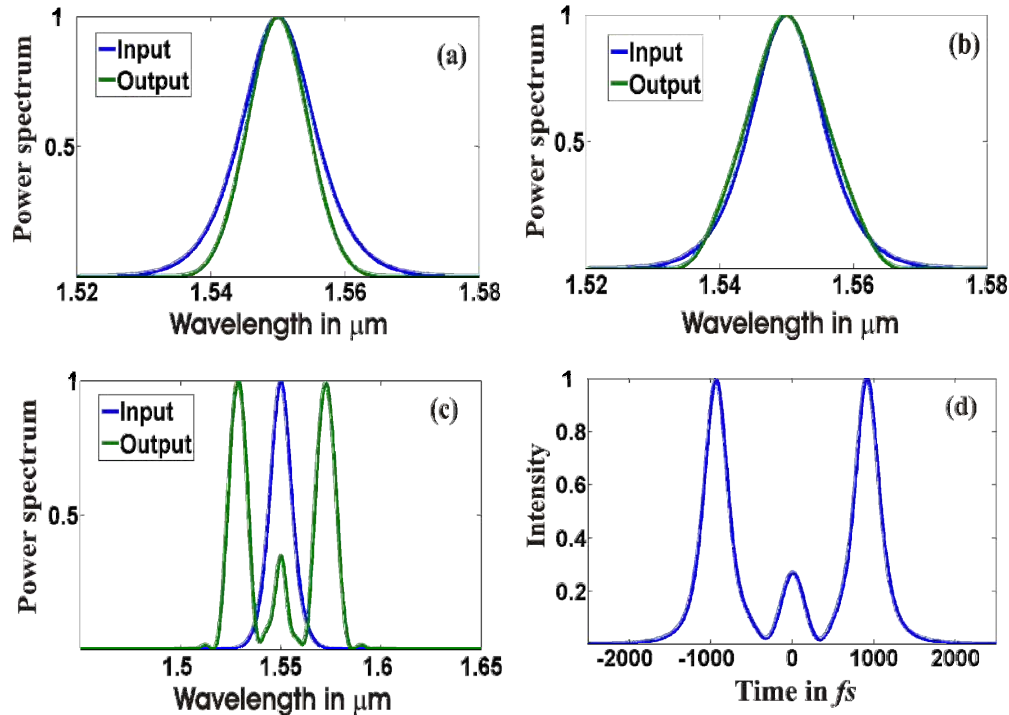


Fig. 4. (a) Input and output soliton power spectra corresponding to the case shown in (a) Fig.3 (a) ; (b) Fig.3.(b) ; (c) and (d) spectral generation and intensity profile for an  $N = 3$  soliton ( $50\text{ W}$  peak power) at  $L \approx 5\text{ mm}$

In conclusion we have shown that optical solitons can exist in dispersion-inverted highly-nonlinear  $AlGaAs$  nanowires. These soliton waves are possible at very low power levels in spite of strong dispersion and can form in millimeter long nanowire structures. The intensity and spectral evolution of solitons propagating in such  $AlGaAs$  nanowaveguides was investigated in the presence of loss, multiphoton absorption and higher-order dispersion.